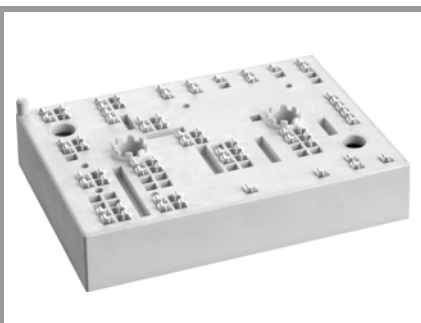


SKiiP 38NAB12T4V1



MiniSKiiP® 3

Converter-Inverter-Brake (CIB)

SKiiP 38NAB12T4V1

Features*

- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

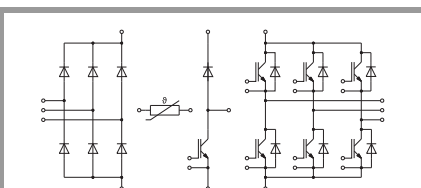
Typical Applications

- Inverter up to 41 kVA
- Typical motor power 22 kW

Remarks

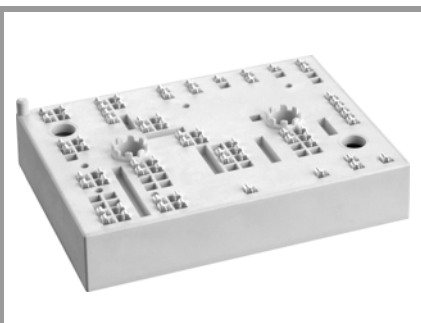
- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +150^\circ\text{C}$)
- For short circuit: Soft R_{Goff} recommended
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.

| Absolute Maximum Ratings | | | | |
|-----------------------------|--|---------------------------|-------------|------------------|
| Symbol | Conditions | | Values | Unit |
| Inverter - IGBT | | | | |
| V_{CES} | $T_j = 25^\circ\text{C}$ | | 1200 | V |
| I_C | $\lambda_{paste}=0.8 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 115 | A |
| | | $T_j = 175^\circ\text{C}$ | 93 | A |
| I_C | $\lambda_{paste}=2.5 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 140 | A |
| | | $T_j = 175^\circ\text{C}$ | 114 | A |
| I_{Chom} | | | 100 | A |
| I_{CRM} | | | 300 | A |
| V_{GES} | | | -20 ... 20 | V |
| t_{psc} | $V_{CC} = 800 \text{ V}$ | $T_j = 150^\circ\text{C}$ | 10 | μs |
| | $V_{GE} \leq 15 \text{ V}$ | | | |
| | $V_{CES} \leq 1200 \text{ V}$ | | | |
| T_j | | | -40 ... 175 | $^\circ\text{C}$ |
| Chopper - IGBT | | | | |
| V_{CES} | $T_j = 25^\circ\text{C}$ | | 1200 | V |
| I_C | $\lambda_{paste}=0.8 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 115 | A |
| | | $T_j = 175^\circ\text{C}$ | 93 | A |
| I_C | $\lambda_{paste}=2.5 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 140 | A |
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| I_{Chom} | | | 100 | A |
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| | $V_{GE} \leq 15 \text{ V}$ | | | |
| | $V_{CES} \leq 1200 \text{ V}$ | | | |
| T_j | | | -40 ... 175 | $^\circ\text{C}$ |
| Inverse - Diode | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | | 1200 | V |
| I_F | $\lambda_{paste}=0.8 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 99 | A |
| | | $T_j = 175^\circ\text{C}$ | 79 | A |
| I_F | $\lambda_{paste}=2.5 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 116 | A |
| | | $T_j = 175^\circ\text{C}$ | 93 | A |
| I_{FRM} | | | 300 | A |
| I_{FSM} | $t_p = 10 \text{ ms, sin } 180^\circ, T_j = 150^\circ\text{C}$ | | 550 | A |
| T_j | | | -40 ... 175 | $^\circ\text{C}$ |
| Freewheeling - Diode | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | | 1200 | V |
| I_F | $\lambda_{paste}=0.8 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 100 | A |
| | | $T_j = 175^\circ\text{C}$ | 79 | A |
| I_F | $\lambda_{paste}=2.5 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 116 | A |
| | | $T_j = 175^\circ\text{C}$ | 93 | A |
| I_{FRM} | | | 300 | A |
| I_{FSM} | $t_p = 10 \text{ ms, sin } 180^\circ, T_j = 150^\circ\text{C}$ | | 550 | A |
| T_j | | | -40 ... 175 | $^\circ\text{C}$ |



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SKiiP 38NAB12T4V1



MiniSKiiP® 3

Converter-Inverter-Brake (CIB)

SKiiP 38NAB12T4V1

Features*

- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

Typical Applications

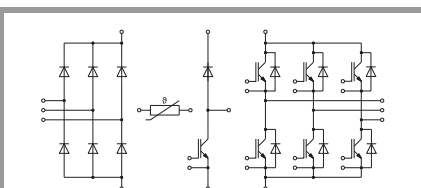
- Inverter up to 41 kVA
- Typical motor power 22 kW

Remarks

- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +150^\circ\text{C}$)
- For short circuit: Soft R_{Goff} recommended
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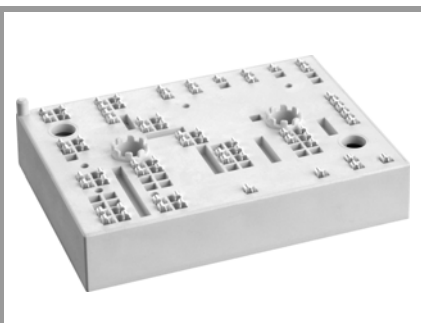
| Absolute Maximum Ratings | | | | |
|--------------------------|---|---------------------------|-------------|----------------------|
| Symbol | Conditions | | Values | Unit |
| Rectifier - Diode | | | | |
| V_{RRM} | $T_j = 25^\circ\text{C}$ | | 1600 | V |
| I_F | $\lambda_{paste}=0.8 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 117 | A |
| | | $T_j = 150^\circ\text{C}$ | 86 | A |
| I_F | $\lambda_{paste}=2.5 \text{ W/(mK)}$ | $T_s = 25^\circ\text{C}$ | 136 | A |
| | | $T_j = 150^\circ\text{C}$ | 101 | A |
| I_{FSM} | $t_p = 10 \text{ ms}$ $\sin 180^\circ$ | $T_j = 25^\circ\text{C}$ | 1000 | A |
| | | $T_j = 150^\circ\text{C}$ | 890 | A |
| i^2t | $t_p = 10 \text{ ms}$ $\sin 180^\circ$ | $T_j = 25^\circ\text{C}$ | 5000 | A^2s |
| | | $T_j = 150^\circ\text{C}$ | 3960 | A^2s |
| T_j | | | -40 ... 150 | $^\circ\text{C}$ |
| Module | | | | |
| $I_{t(RMS)}$ | $T_{terminal} = 80^\circ\text{C}$, 20 A per spring | | 80 | A |
| T_{stg} | module without TIM | | -40 ... 125 | $^\circ\text{C}$ |
| V_{isol} | AC sinus 50 Hz, 1 min | | 2500 | V |

| Characteristics | | | | | | |
|------------------------|--|---------------------------|------|------|------|------------------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| Inverter - IGBT | | | | | | |
| $V_{CE(sat)}$ | $I_C = 100 \text{ A}$ $V_{GE} = 15 \text{ V}$ chipelevel | $T_j = 25^\circ\text{C}$ | 1.80 | 2.05 | | V |
| | | $T_j = 150^\circ\text{C}$ | 2.20 | 2.40 | | V |
| V_{CE0} | chipelevel | $T_j = 25^\circ\text{C}$ | 0.80 | 0.90 | | V |
| | | $T_j = 150^\circ\text{C}$ | 0.70 | 0.80 | | V |
| r_{CE} | $V_{GE} = 15 \text{ V}$ chipelevel | $T_j = 25^\circ\text{C}$ | 10 | 12 | | $\text{m}\Omega$ |
| | | $T_j = 150^\circ\text{C}$ | 15 | 16 | | $\text{m}\Omega$ |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}$, $I_C = 4 \text{ mA}$ | | 5 | 5.8 | 6.5 | V |
| I_{CES} | $V_{GE} = 0 \text{ V}$, $V_{CE} = 1200 \text{ V}$, $T_j = 25^\circ\text{C}$ | | | | 1 | mA |
| C_{ies} | $V_{CE} = 25 \text{ V}$ $V_{GE} = 0 \text{ V}$ | $f = 1 \text{ MHz}$ | 6.15 | | | nF |
| C_{oes} | | $f = 1 \text{ MHz}$ | 0.41 | | | nF |
| C_{res} | | $f = 1 \text{ MHz}$ | 0.35 | | | nF |
| Q_G | $V_{GE} = -8 \text{ V} \dots +15 \text{ V}$ | | | 565 | | nC |
| R_{Gint} | $T_j = 25^\circ\text{C}$ | | | 7.5 | | Ω |
| $t_{d(on)}$ | $V_{CC} = 600 \text{ V}$ $I_C = 100 \text{ A}$ $R_{G on} = 1 \Omega$ $R_{G off} = 1 \Omega$ | $T_j = 150^\circ\text{C}$ | 160 | | | ns |
| t_r | | $T_j = 150^\circ\text{C}$ | 35 | | | ns |
| E_{on} | | $T_j = 150^\circ\text{C}$ | 11.2 | | | mJ |
| $t_{d(off)}$ | | $T_j = 150^\circ\text{C}$ | 390 | | | ns |
| t_f | | $T_j = 150^\circ\text{C}$ | 75 | | | ns |
| E_{off} | $V_{GE} = +15/-15 \text{ V}$ | | | 10 | | mJ |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=0.8 \text{ W/(mK)}$ | | | 0.48 | | K/W |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=2.5 \text{ W/(mK)}$ | | | 0.34 | | K/W |



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Features*

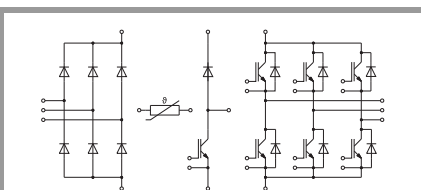
- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

Typical Applications

- Inverter up to 41 kVA
- Typical motor power 22 kW

Remarks

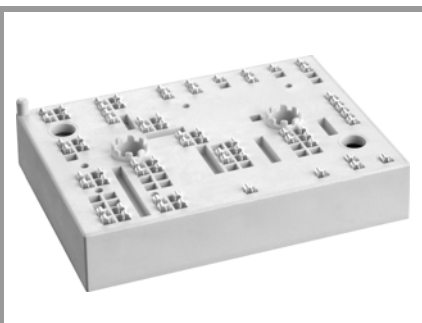
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| Characteristics | | | | | | |
|-----------------------------|---|---------------------------|------|------|------|---------------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| Chopper - IGBT | | | | | | |
| $V_{CE(sat)}$ | $I_C = 100\text{ A}$ $V_{GE} = 15\text{ V}$ chipelevel | $T_j = 25^\circ\text{C}$ | | 1.80 | 2.05 | V |
| | | $T_j = 150^\circ\text{C}$ | | 2.20 | 2.40 | V |
| V_{CE0} | chipelevel | $T_j = 25^\circ\text{C}$ | | 0.80 | 0.90 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.70 | 0.80 | V |
| r_{CE} | $V_{GE} = 15\text{ V}$ chipelevel | $T_j = 25^\circ\text{C}$ | | 10 | 12 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 15 | 16 | m Ω |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}, I_C = 4\text{ mA}$ | | 5 | 5.8 | 6.5 | V |
| I_{CES} | $V_{GE} = 0\text{ V}, V_{CE} = 1200\text{ V}, T_j = 25^\circ\text{C}$ | | | | 1 | mA |
| C_{ies} | $V_{CE} = 25\text{ V}$ $V_{GE} = 0\text{ V}$ | $f = 1\text{ MHz}$ | | 6.15 | | nF |
| C_{oes} | | $f = 1\text{ MHz}$ | | 0.41 | | nF |
| C_{res} | | $f = 1\text{ MHz}$ | | 0.35 | | nF |
| Q_G | $V_{GE} = -8\text{ V} \dots +15\text{ V}$ | | | 565 | | nC |
| R_{Gint} | $T_j = 25^\circ\text{C}$ | | | 7.5 | | Ω |
| $t_{d(on)}$ | $V_{CC} = 600\text{ V}$ $I_C = 100\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 160 | | ns |
| t_r | | $T_j = 150^\circ\text{C}$ | | 35 | | ns |
| E_{on} | $R_{Gon} = 1\ \Omega$ $R_{Goff} = 1\ \Omega$ | $T_j = 150^\circ\text{C}$ | | 11.2 | | mJ |
| $t_{d(off)}$ | | $T_j = 150^\circ\text{C}$ | | 390 | | ns |
| t_f | $V_{GE} = +15/-15\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 75 | | ns |
| E_{off} | | $T_j = 150^\circ\text{C}$ | | 10 | | mJ |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 0.48 | | K/W |
| $R_{th(j-s)}$ | per IGBT, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 0.34 | | K/W |
| Inverse - Diode | | | | | | |
| $V_F = V_{EC}$ | $I_F = 100\text{ A}$ $V_{GE} = 0\text{ V}$ chipelevel | $T_j = 25^\circ\text{C}$ | | 2.20 | 2.52 | V |
| | | $T_j = 150^\circ\text{C}$ | | 2.15 | 2.47 | V |
| V_{F0} | chipelevel | $T_j = 25^\circ\text{C}$ | | 1.30 | 1.50 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.90 | 1.10 | V |
| r_F | chipelevel | $T_j = 25^\circ\text{C}$ | | 9.0 | 10 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 13 | 14 | m Ω |
| I_{RRM} | $I_F = 100\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 82 | | A |
| Q_{rr} | $di/dt_{off} = 2400\text{ A}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 16.4 | | μC |
| E_{rr} | $V_{GE} = -15\text{ V}$ $V_{CC} = 600\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 6.5 | | mJ |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 0.66 | | K/W |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 0.52 | | K/W |
| Freewheeling - Diode | | | | | | |
| $V_F = V_{EC}$ | $I_F = 100\text{ A}$ $V_{GE} = 0\text{ V}$ chipelevel | $T_j = 25^\circ\text{C}$ | | 2.20 | 2.52 | V |
| | | $T_j = 150^\circ\text{C}$ | | 2.15 | 2.47 | V |
| V_{F0} | chipelevel | $T_j = 25^\circ\text{C}$ | | 1.30 | 1.50 | V |
| | | $T_j = 150^\circ\text{C}$ | | 0.90 | 1.10 | V |
| r_F | chipelevel | $T_j = 25^\circ\text{C}$ | | 9.0 | 10 | m Ω |
| | | $T_j = 150^\circ\text{C}$ | | 13 | 14 | m Ω |
| I_{RRM} | $I_F = 100\text{ A}$ | $T_j = 150^\circ\text{C}$ | | 82 | | A |
| Q_{rr} | $di/dt_{off} = 2400\text{ A}/\mu\text{s}$ | $T_j = 150^\circ\text{C}$ | | 16.4 | | μC |
| E_{rr} | $V_{GE} = -15\text{ V}$ $V_{CC} = 600\text{ V}$ | $T_j = 150^\circ\text{C}$ | | 6.5 | | mJ |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$ | | | 0.66 | | K/W |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$ | | | 0.52 | | K/W |

SKiiP 38NAB12T4V1



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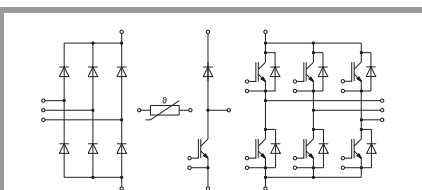
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- Max. case temperature limited to $T_C=125^\circ\text{C}$
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- For short circuit: Soft R_{Goff} recommended
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.

| Characteristics | | | | | | |
|---------------------------|---|---------------------------|------|------------------|------|------------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| Rectifier - Diode | | | | | | |
| $V_F = V_{EC}$ | $I_F = 45 \text{ A}$ chipelevel | $T_j = 25^\circ\text{C}$ | | 1.00 | 1.21 | V |
| | | $T_j = 125^\circ\text{C}$ | | 0.90 | 1.10 | V |
| V_{F0} | chipelevel | $T_j = 25^\circ\text{C}$ | | 0.88 | 0.98 | V |
| | | $T_j = 125^\circ\text{C}$ | | 0.73 | 0.83 | V |
| r_F | chipelevel | $T_j = 25^\circ\text{C}$ | | 2.7 | 5.1 | m Ω |
| | | $T_j = 125^\circ\text{C}$ | | 3.8 | 6.0 | m Ω |
| I_R | $T_j = 145^\circ\text{C}, V_{RRM}$ | | | | 1.1 | mA |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=0.8 \text{ W/(mK)}$ | | | 0.7 | | K/W |
| $R_{th(j-s)}$ | per Diode, $\lambda_{paste}=2.5 \text{ W/(mK)}$ | | | 0.56 | | K/W |
| Module | | | | | | |
| M_s | to heat sink | | 2 | | 2.5 | Nm |
| w | | | | 82 | | g |
| L_{CE} | | | | - | | nH |
| Temperature Sensor | | | | | | |
| R_{100} | $T_r=100^\circ\text{C} (R_{25}=1000\Omega)$ | | | 1670 \pm 3% | | Ω |
| $R_{(T)}$ | $R_{(T)}=1000\Omega[1+A(T-25^\circ\text{C})+B(T-25^\circ\text{C})^2]$, $A = 7.635 \cdot 10^{-3} \text{ }^\circ\text{C}^{-1}$, $B = 1.731 \cdot 10^{-5} \text{ }^\circ\text{C}^{-2}$ | | | | | |



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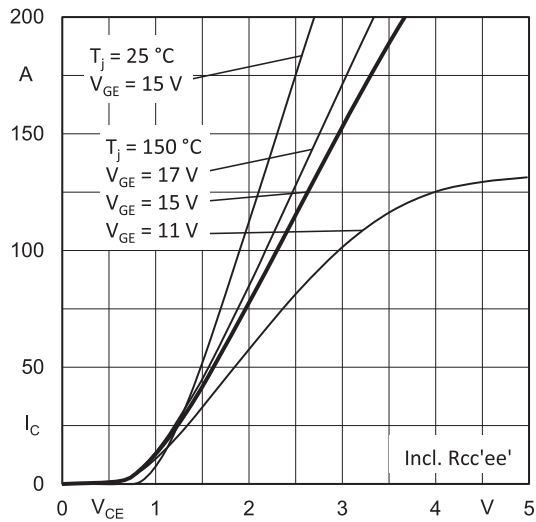


Fig. 1: Typ. output characteristic

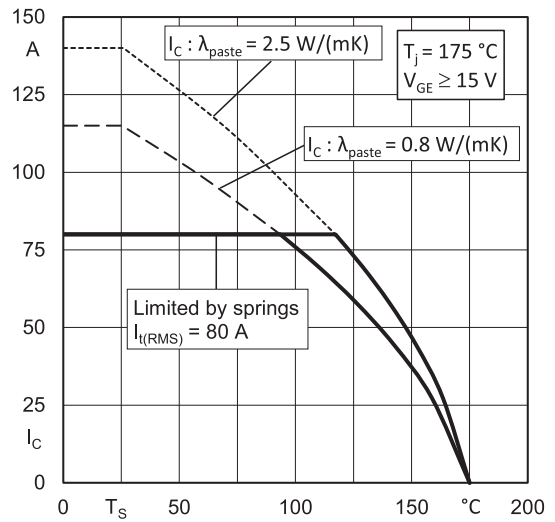


Fig. 2: Typ. rated current vs. temperature $I_C = f(T_s)$

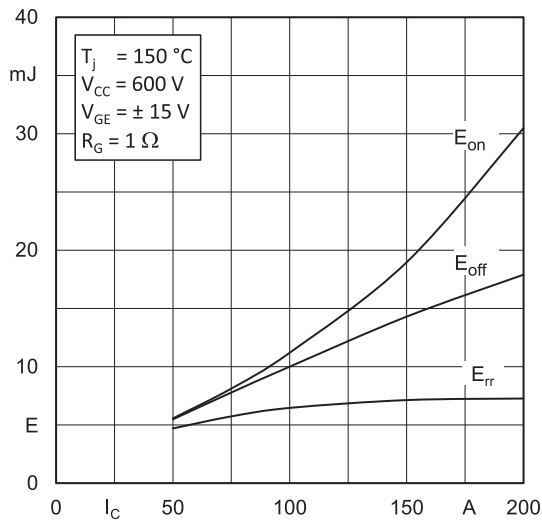


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

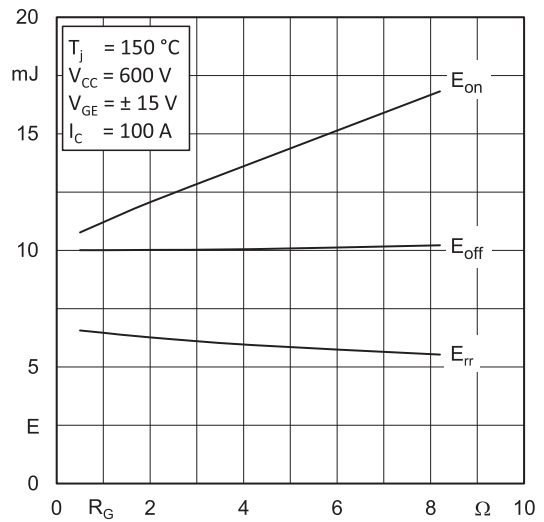


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

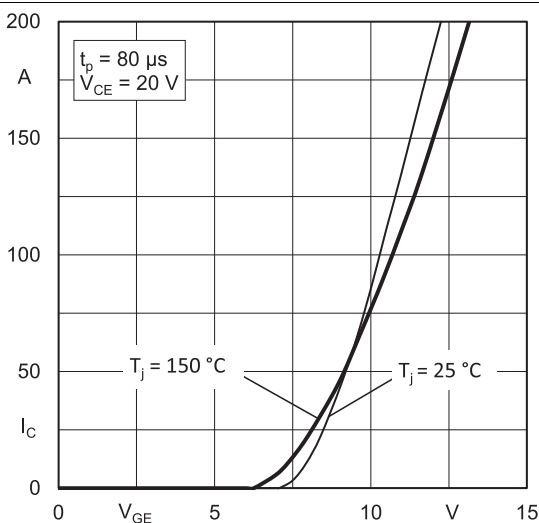


Fig. 5: Typ. transfer characteristic

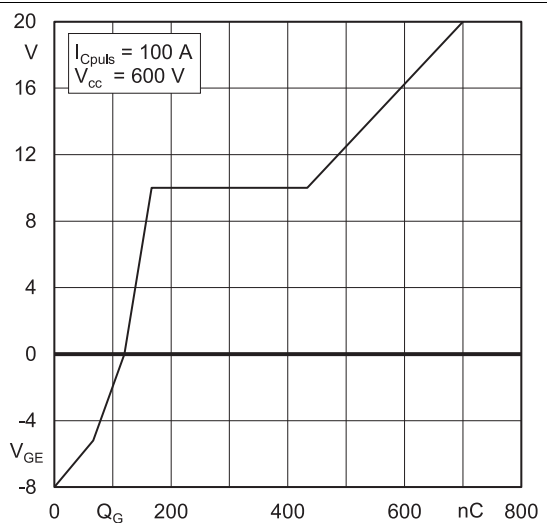
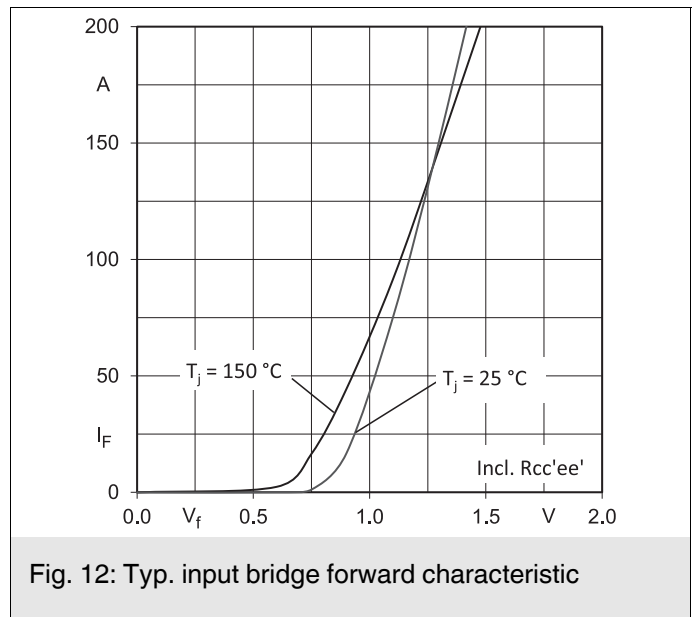
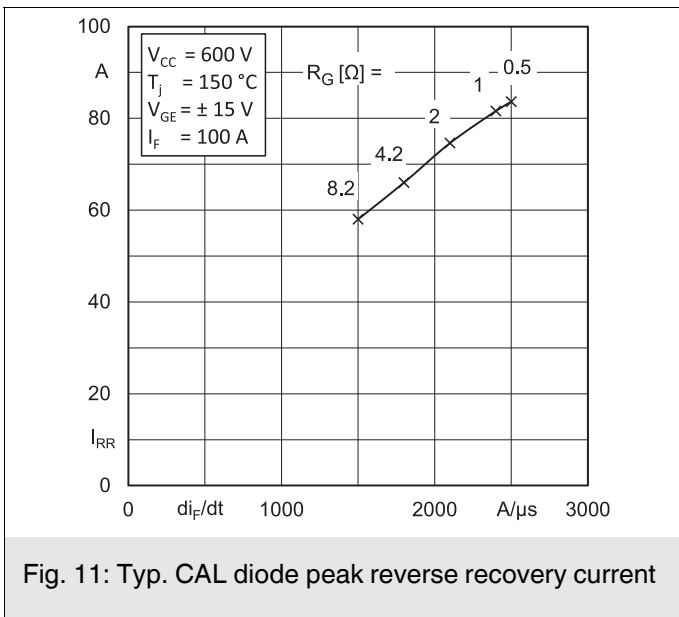
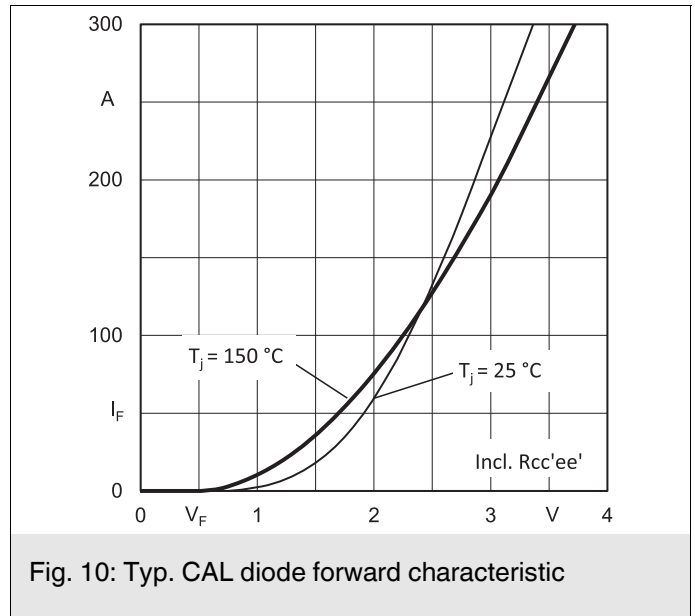
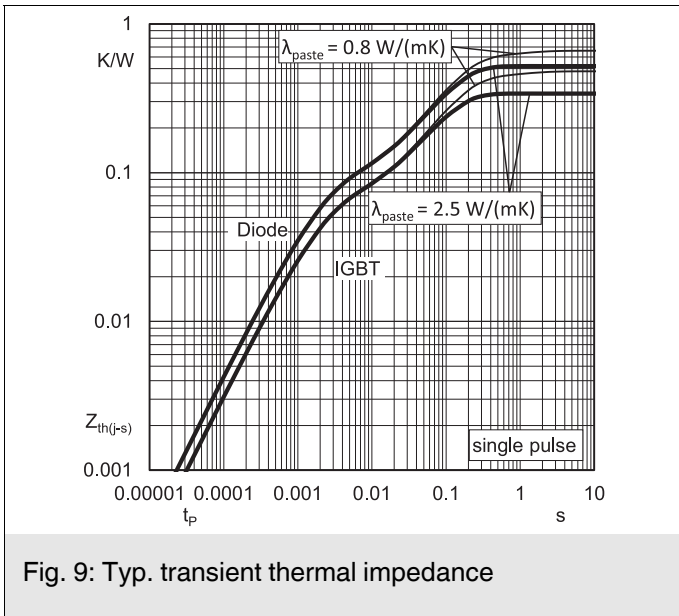
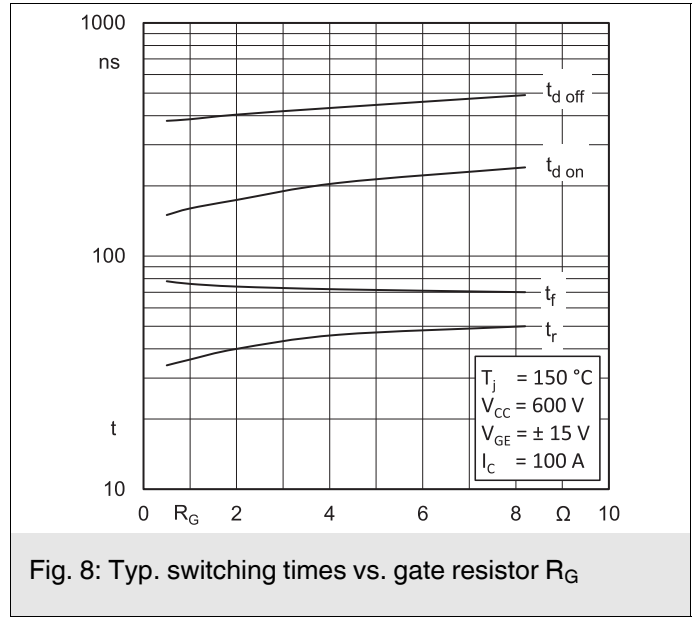
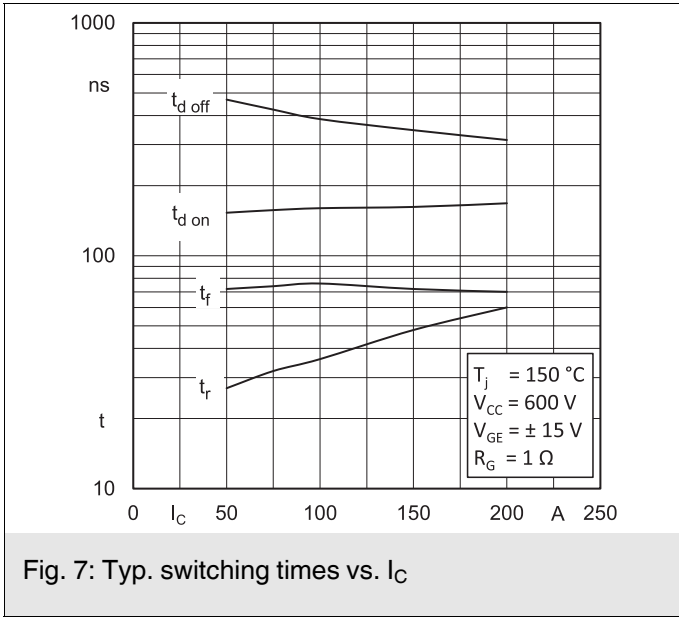
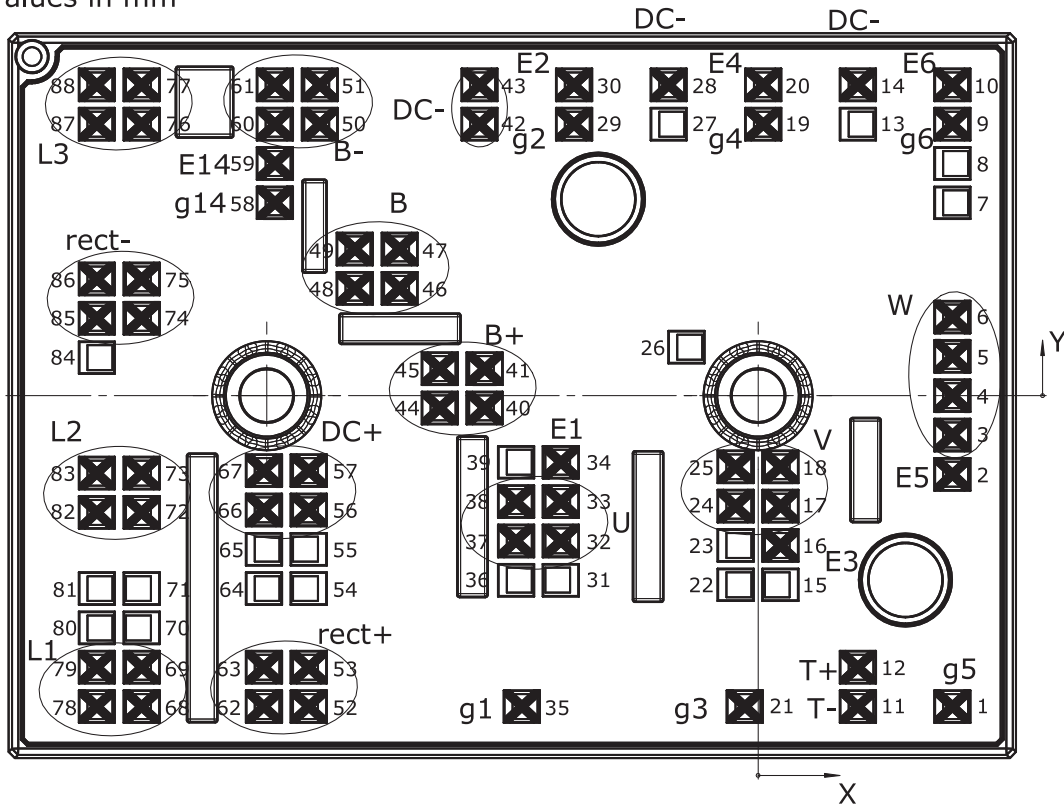


Fig. 6: Typ. gate charge characteristic

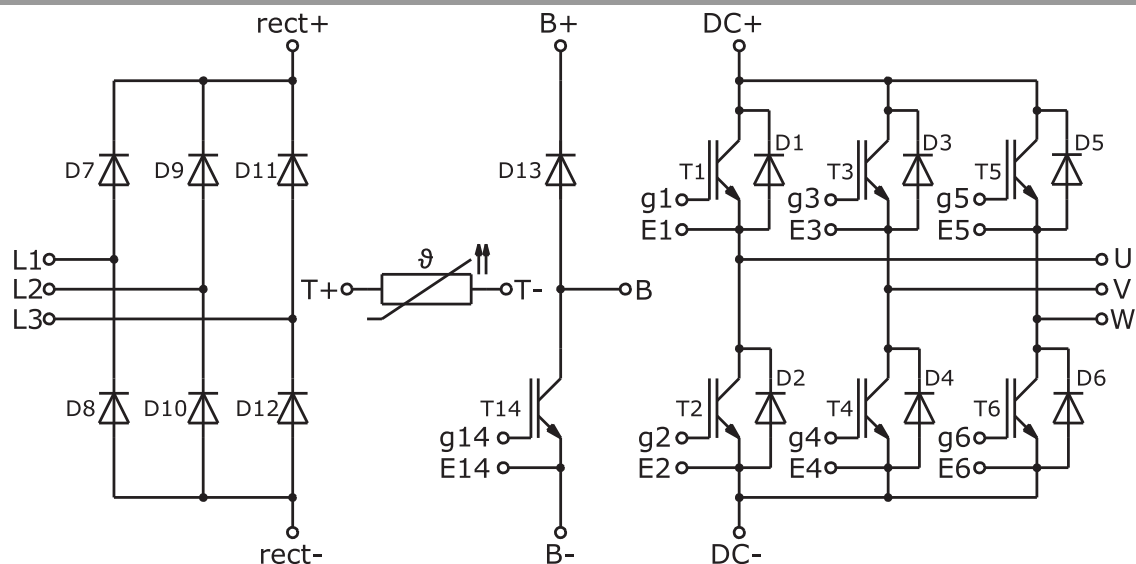


| Pin out | | | | | | | | | | | |
|---------|--------|--------|----------|-----|--------|--------|----------|-----|--------|--------|----------|
| Pin | X | Y | Function | Pin | X | Y | Function | Pin | X | Y | Function |
| 1 | 15,83 | -25,30 | g5 | 31 | -16,05 | -15,02 | | 61 | -39,33 | 25,30 | B- |
| 2 | 15,83 | -6,40 | E5 | 32 | -16,05 | -11,82 | U | 62 | -40,23 | -25,30 | rect+ |
| 3 | 15,83 | -3,20 | W | 33 | -16,05 | -8,62 | U | 63 | -40,23 | -22,10 | rect+ |
| 4 | 15,83 | 0 | W | 34 | -16,05 | -5,42 | E1 | 64 | -40,23 | -15,70 | |
| 5 | 15,83 | 3,20 | W | 35 | -19,23 | -25,30 | g1 | 65 | -40,23 | -12,50 | |
| 6 | 15,83 | 6,40 | W | 36 | -19,70 | -15,02 | | 66 | -40,23 | -9,30 | DC+ |
| 7 | 15,83 | 15,70 | | 37 | -19,70 | -11,82 | U | 67 | -40,23 | -6,10 | DC+ |
| 8 | 15,83 | 18,90 | | 38 | -19,70 | -8,62 | U | 68 | -50,18 | -25,30 | L1 |
| 9 | 15,83 | 22,10 | g6 | 39 | -19,70 | -5,42 | | 69 | -50,18 | -22,10 | L1 |
| 10 | 15,83 | 25,30 | E6 | 40 | -22,26 | -1,00 | B+ | 70 | -50,18 | -18,90 | |
| 11 | 8,13 | -25,30 | T- | 41 | -22,26 | 2,20 | B+ | 71 | -50,18 | -15,70 | |
| 12 | 8,13 | -22,10 | T+ | 42 | -22,68 | 22,10 | DC- | 72 | -50,18 | -9,50 | L2 |
| 13 | 8,13 | 22,10 | | 43 | -22,68 | 25,30 | DC- | 73 | -50,18 | -6,30 | L2 |
| 14 | 8,13 | 25,30 | DC- | 44 | -25,91 | -1,00 | B+ | 74 | -50,18 | 6,30 | rect- |
| 15 | 1,83 | -15,39 | | 45 | -25,91 | 2,20 | B+ | 75 | -50,18 | 9,50 | rect- |
| 16 | 1,83 | -12,19 | E3 | 46 | -29,18 | 8,74 | B | 76 | -50,18 | 22,10 | L3 |
| 17 | 1,83 | -8,99 | V | 47 | -29,18 | 11,94 | B | 77 | -50,18 | 25,30 | L3 |
| 18 | 1,83 | -5,79 | V | 48 | -32,83 | 8,74 | B | 78 | -53,83 | -25,30 | L1 |
| 19 | 0,43 | 22,10 | g4 | 49 | -32,83 | 11,94 | B | 79 | -53,83 | -22,10 | L1 |
| 20 | 0,43 | 25,30 | E4 | 50 | -35,68 | 22,10 | B- | 80 | -53,83 | -18,90 | |
| 21 | -1,08 | -25,30 | g3 | 51 | -35,68 | 25,30 | B- | 81 | -53,83 | -15,70 | |
| 22 | -1,83 | -15,39 | | 52 | -36,58 | -25,30 | rect+ | 82 | -53,83 | -9,50 | L2 |
| 23 | -1,83 | -12,19 | | 53 | -36,58 | -22,10 | rect+ | 83 | -53,83 | -6,30 | L2 |
| 24 | -1,83 | -8,99 | V | 54 | -36,58 | -15,70 | | 84 | -53,83 | 3,10 | |
| 25 | -1,83 | -5,79 | V | 55 | -36,58 | -12,50 | | 85 | -53,83 | 6,30 | rect- |
| 26 | -5,83 | 3,95 | | 56 | -36,58 | -9,30 | DC+ | 86 | -53,83 | 9,50 | rect- |
| 27 | -7,28 | 22,10 | | 57 | -36,58 | -6,10 | DC+ | 87 | -53,83 | 22,10 | L3 |
| 28 | -7,28 | 25,30 | DC- | 58 | -39,33 | 15,70 | g14 | 88 | -53,83 | 25,30 | L3 |
| 29 | -14,98 | 22,10 | g2 | 59 | -39,33 | 18,90 | E14 | | | | |
| 30 | -14,98 | 25,30 | E2 | 60 | -39,33 | 22,10 | B- | | | | |

all values in mm



Pinout and Dimensions



Pinout

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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